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10/677,573 10/02/2003 John M. Grant SC12480TP 9304 23125 7590 11/03/2004 EXAMINER FREESCALE SEMICONDUCTOR, INC. LAW DEPARTMENT 7700 WEST PARMER LANE MD:TX32/PL02 ART UNIT PAPER NUMBER	APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
FREESCALE SEMICONDUCTOR, INC. LAW DEPARTMENT TRAN, MINH LOAN	10/677,573	10/02/2003	John M. Grant	SC12480TP	9304
LAW DEPARTMENT	23125	7590 11/03/2004	EXAMINER		
			TRAN, MINH LOAN		
	7700 WEST PARMER LANE MD:TX32/PL02			ART UNIT	PAPER NUMBER
AUSTIN, TX 78729 2826	AUSTIN, TX	78729		2826	

DATE MAILED: 11/03/2004

Please find below and/or attached an Office communication concerning this application or proceeding.

,		Application No.	Applicant(s)				
		10/677,573	GRANT ET AL.				
	Office Action Summary	Examiner	Art Unit				
		Minh-Loan T. Tran	2826				
Period fo	The MAILING DATE of this communication Reply	on appears on the cover shee	et with the correspondence a	ddress			
THE - Exte after - If the - If NC - Failt Any	IORTENED STATUTORY PERIOD FOR MAILING DATE OF THIS COMMUNICAT ensions of time may be available under the provisions of 37° SIX (6) MONTHS from the mailing date of this communicate period for reply specified above is less than thirty (30) day of period for reply is specified above, the maximum statutory are to reply within the set or extended period for reply will, by reply received by the Office later than three months after the period patent term adjustment. See 37 CFR 1.704(b).	TION. CFR 1.136(a). In no event, however, matton. s, a reply within the statutory minimum or period will apply and will expire SIX (6) y statute, cause the application to becon	ay a reply be timely filed of thirty (30) days will be considered tim MONTHS from the mailing date of this ne ABANDONED (35 U.S.C. § 133).	ety. communication.			
Status							
1)🛛	Responsive to communication(s) filed or	n 12 July 2004.	•				
2a)□	_ · _	This action is non-final.					
3)⊠							
Disposit	ion of Claims						
4)⊠ 5)□ 6)□ 7)⊠ 8)□	Claim(s) <u>1-20</u> is/are pending in the appli 4a) Of the above claim(s) <u>1-10</u> is/are with Claim(s) is/are allowed. Claim(s) is/are rejected. Claim(s) <u>11-20</u> is/are objected to. Claim(s) are subject to restriction	ndrawn from consideration.		· .			
Applicat	ion Papers	•					
10)⊠	The specification is objected to by the Ex The drawing(s) filed on <u>02 October 2003</u> Applicant may not request that any objection Replacement drawing sheet(s) including the The oath or declaration is objected to by	is/are: a) accepted or b) to the drawing(s) be held in abcorrection is required if the draw	eyance. See 37 CFR 1.85(a). ving(s) is objected to. See 37 C	CFR 1.121(d).			
Priority (under 35 U.S.C. § 119						
12)□ a)	Acknowledgment is made of a claim for for All b) Some * c) None of: 1. Certified copies of the priority doct 2. Certified copies of the priority doct 3. Copies of the certified copies of the application from the International Eace the attached detailed Office action for	uments have been received. uments have been received e priority documents have be Bureau (PCT Rule 17.2(a)).	in Application No een received in this Nationa	ıl Stage			
Attachmen	t(s)						
	e of References Cited (PTO-892)	4) Intervi	ew Summary (PTO-413)				
3) 🔯 Infori	e of Draftsperson's Patent Drawing Review (PTO-9 mation Disclosure Statement(s) (PTO-1449 or PTO/ or No(s)/Mail Date <u>10/02/03</u> .		No(s)/Mail Date of Informal Patent Application (PT	O-152)			

DETAILED ACTION

Election/Restrictions

1. Applicant's election without traverse of Group II, claims 11-20 in the reply filed on 07/12/2004 is acknowledged.

Information Disclosure Statement

2. The Information Disclosure Statement filed on 10/02/2003 has been considered.

Oath/Declaration

3. The oath or declaration filed on 10/02/2003 is acceptable.

Drawings

4. The drawings are objected to under 37 CFR 1.83(a). The drawings must show every feature of the invention specified in the claims. Therefore, "the second diameter being **equal to** the first diameter" or "the fourth diameter being **equal to** the third diameter" as recited in claims 11,14, 15, 16, 18, 19 must be shown or the feature(s) canceled from the claim(s). No new matter should be entered.

Corrected drawing sheets in compliance with 37 CFR 1.121(d) are required in reply to the Office action to avoid abandonment of the application. Any amended replacement drawing sheet should include all of the figures appearing on the immediate prior version of the sheet, even if only one figure is being amended. The figure or figure number of an amended drawing should not be labeled as "amended." If a drawing figure is to be canceled, the appropriate figure must be removed from the replacement sheet, and where necessary, the remaining figures must be renumbered and appropriate changes made to the brief description of the several views of the drawings for

consistency. Additional replacement sheets may be necessary to show the renumbering of the remaining figures. The replacement sheet(s) should be labeled "Replacement Sheet" in the page header (as per 37 CFR 1.84(c)) so as not to obstruct any portion of the drawing figures. If the changes are not accepted by the examiner, the applicant will be notified and informed of any required corrective action in the next Office action. The objection to the drawings will not be held in abeyance.

Specification

5. The disclosure is objected to because of the following informalities:

Applicants are requested to update the information of the related application on page 1 of the specification.

Appropriate correction is required.

Claim Objections

6. Claims 11-20 are objected to because of the following informalities:

In claim 11, lines 8 and 9, "the second diameter being **equal to or greater than** the first diameter" should be changed to -- the second diameter being **greater than** the first diameter—for being consistent with the drawings.

In claim 14, lines 4 and 5, "the fourth diameter being **equal to or greater than** the third diameter" should be changed to -- the fourth diameter being **greater than** the third diameter -- for being consistent with the drawings.

In claim 15, lines 4 and 5, "the fourth diameter being **equal to or greater than** the third diameter" should be changed to -- the fourth diameter being **greater than** the third diameter -- for being consistent with the drawings.

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In claim 16, line 6, "the second diameter being **equal to or greater than** the first diameter" should be changed to -- the second diameter being **greater than** the first diameter -- for being consistent with the drawings.

In claim 18, lines 4 and 5, "the fourth diameter being equal to or greater than the third diameter" should be changed to -- the fourth diameter being greater than the third diameter -- for being consistent with the drawings.

In claim 19, lines 4 and 5, "the fourth diameter being **equal to or greater than** the third diameter" should be changed to -- the fourth diameter being **greater than** the third diameter -- for being consistent with the drawings.

Appropriate correction is required.

Allowable Subject Matter

7. Claims 11-20 are allowed.

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The prior art of record taken either singly or in combination fails to anticipate or fairly suggest the limitations which the Applicants claim in claims 11-20 in a manner which would warrant a rejection under 35 U.S.C. § 102 or 35 U.S.C. § 103.

There was no prior art found by the examiner that suggested modification or combination with the cited prior art so as to satisfy the combination of the present independent claims 11 and 16; especially, the prior art does not disclose filling the first opening and a portion of the second opening with a first single crystal semiconductor material having a relaxed state by having defects for a controlled depth from the single crystal substrate to a predetermined height; a remainder of the first single crystal semiconductor material not having defects; filling a remaining portion of the second

opening with a second single crystal semiconductor material that is strained by having a predetermined thickness that does not exceed a critical thickness where defects begin to form.

Conclusion

8. This application is in condition for allowance except for the following formal matters noted above.

Prosecution on the merits is closed in accordance with the practice under Ex parte Quayle, 1935 C.D. 11, 453 O.G. 213.

A shortened statutory period for reply to this action is set to expire **TWO**MONTHS from the mailing date of this letter.

9. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Minh-Loan T. Tran whose telephone number is (571) 272-1922. The examiner can normally be reached on Monday-Friday 9:00 AM-5:30 PM.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Nathan J. Flynn can be reached on (571) 272-1915. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

MIt

Minh-Loan T. Tran **Primary Examiner**

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